L Number	Hits	Search Text	DB	Time stamp
151	6	(different adj material).clm. and (gate adj	USPAT;	2004/11/08
,		wiring).clm.	US-PGPUB;	14:47
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
152	5	(different adj material).clm. and (gate adj	USPAT;	2004/11/08
	_	wiring).clm. and (gate adj electrode).clm.	US-PGPUB;	14:50
		(3410 447 0100 407,01111	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
153	1	(different adj material).clm. and (gate adj	USPAT;	2004/11/08
.00		wiring).clm. and (gate adj electrode).clm.	US-PGPUB;	14:49
		and channel.clm.	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
154	44	(different).clm. and (gate adj wiring).clm.	USPAT;	2004/11/08
		and (gate adj electrode).clm.	US-PGPUB;	14:50
		ana (gate au) cicotroachemn	EPO; JPO;	14.50
			DERWENT;	
			IBM_TDB	
155	15	(different).clm. and (gate adj wiring).clm.	USPAT;	2004/11/08
		and (gate adj electrode).clm. and	US-PGPUB;	14:50
		channel.clm.	EPO; JPO;	14.50
			DERWENT;	
			IBM_TDB	
156	10	((electrode or wiring or conductive or	USPAT;	2004/11/08
		conducting or metal) near10	US-PGPUB;	14:53
	;	(different)).clm. and (gate adj wiring).clm.	EPO; JPO;	14:55
		and (gate adj electrode).clm. and	DERWENT;	
		channel.cim.	IBM_TDB	
157	499	(gate adj electrode) same (gate adj wiring)	USPAT;	2004/11/08
	. 400	same channel	US-PGPUB;	14:53
		Same Ghanner	EPO; JPO;	14.55
			DERWENT;	
			IBM_TDB	
158	43	((gate adj electrode) same (gate adj wiring)	USPAT;	2004/11/08
	40	same channel).clm.	US-PGPUB;	14:53
			EPO; JPO;	14.55
			DERWENT;	
			IBM_TDB	
159	1	((gate adj electrode) same (gate adj wiring)	USPAT;	2004/11/08
	•	same channel).clm. and (outside near10	US-PGPUB;	14:55
		channel).clm.	EPO; JPO;	17,55
		- vuenuelhoum	DERWENT;	
			IBM_TDB	
160	22	((gate adj electrode) same (gate adj wiring)	_	2004/44/00
.55	44		USPAT;	2004/11/08
		same channel).clm. and ((gate adj wiring)	US-PGPUB;	14:55
		near10 (conductive or conducting or	EPO; JPO;	
		material)).clm.	DERWENT; IBM_TDB	

161	15	((gate adj electrode) same (gate adj wiring)	USPAT;	2004/11/08
i		same channel).clm. and ((gate adj wiring)	US-PGPUB;	14:56
		near10 (conductive or conducting or	EPO; JPO;	
		material)).clm. and (channel near2	DERWENT;	
		region).clm.	IBM_TDB	
162	9	((gate adj electrode) same (gate adj wiring)	USPAT;	2004/11/08
		same (channel near2 region)).clm. and	US-PGPUB;	14:56
		((gate adj wiring) near10 (conductive or	EPO; JPO;	
		conducting or material)).clm. and (channel	DERWENT;	
		near2 region).clm.	IBM_TDB	
163	9	((gate adj electrode) same (gate adj wiring)	USPAT;	2004/11/08
		same (channel near2 region)).clm. and	US-PGPUB;	14:59
		((gate adj wiring) near10 (conductive or	EPO; JPO;	
		conducting or material)).clm.	DERWENT;	
			IBM_TDB	
164	59	(gate adj electrode) near10 (gate adj	USPAT;	2004/11/08
		wiring) near10 (different adj material)	US-PGPUB;	15:00
			EPO; JPO;	
		·	DERWENT;	
			IBM_TDB	
165	0	((gate adj electrode) near10 (gate adj	USPAT;	2004/11/08
		wiring) near10 (different adj material)).clm.	US-PGPUB;	15:01
,			EPO; JPO;	
		, '	DERWENT;	
			IBM_TDB	
166	59	((gate adj electrode) near10 (gate adj	USPAT;	2004/11/08
		wiring) near10 (different adj material))	US-PGPUB;	15:02
			EPO; JPO;	
	1		DERWENT;	
			IBM_TDB	
167	10	((gate adj electrode) near10 (gate adj	USPAT;	2004/11/08
		wiring) near10 (different)).clm.	US-PGPUB;	15:03
			EPO; JPO;	
			DERWENT;	,
			IBM_TDB	
168	5	(gate adj electrode).clm. and (gate adj	USPAT;	2004/11/08
		wiring).clm. and (different adj	US-PGPUB;	15:05
		material).clm.	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
169	226	(gate adj wiring).clm. and (gate adj	USPAT;	2004/11/08
		electrode).clm.	US-PGPUB;	15:06
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
170	69	(gate adj wiring).clm. and (gate adj	USPAT;	2004/11/08
		electrode).clm. and (channel near2	US-PGPUB;	15:06
		region).clm.	EPO; JPO;	
			DERWENT;	
			IBM_TDB	

171	10 `	(gate adj wiring).clm. and (gate adj	USPAT;	2004/11/08
		electrode).clm. and (channel near2	US-PGPUB;	15:07
		region).clm. and (first adj (conductive or	EPO; JPO;	
		conducting) adj layer).clm.	DERWENT;	
		<b>3</b> , <b>3</b> ,	IBM_TDB	
172	0	(gate adj wiring).clm. and (gate adj	USPAT;	2004/11/08
		electrode).cim. and (channel near2	US-PGPUB;	15:07
		region).clm. and (first adj (conductive or	EPO; JPO;	
		conducting) adj layer).clm. and (second adj	DERWENT;	'
		(conductive adj conducting) adj layer).clm.	IBM_TDB	
173	o	(gate adj wiring).clm. and (gate adj	USPAT;	2004/11/08
		electrode).clm. and (channel).clm. and (first	US-PGPUB;	15:07
		adj (conductive or conducting) adj	EPO; JPO;	13.07
		layer).clm. and (second adj (conductive adj	DERWENT;	
			· ·	
174	25	conducting) adj layer).clm.	IBM_TDB	2004/44/00
1/4	25	(gate adj wiring).clm. and (gate adj	USPAT;	2004/11/08
		electrode).clm. and (channel).clm. and	US-PGPUB;	15:09
		((conductive or conducting) adj layer).clm.	EPO; JPO;	
			DERWENT;	,
			IBM_TDB	
175	25	(gate adj wiring).clm. and (gate adj	USPAT;	2004/11/08
		electrode).clm. and (channel).clm. and	US-PGPUB;	15:09
	1	((conductive or conducting) adj layer).clm.	EPO; JPO;	
		and channel.clm.	DERWENT;	
	]		IBM_TDB	
176	19	(gate adj wiring).clm. and (gate adj	USPAT;	2004/11/08
		electrode).clm. and (channel).clm. and	US-PGPUB;	15:10
		((conductive or conducting) adj layer).clm.	EPO; JPO;	
		and (channel near2 region).clm.	DERWENT;	
			IBM_TDB	
177	5	(gate adj wiring).clm. and (gate adj	USPAT;	2004/11/08
		electrode).clm. and (channel).clm. and	US-PGPUB;	15:14
		((conductive or conducting) adj layer).clm.	EPO; JPO;	
		and (channel near2 region).clm. and (wiring	DERWENT;	
		near10 channel).clm.	IBM_TDB	
178	4	(gate adj wiring).clm. and (gate adj	USPAT;	2004/11/08
		electrode).clm. and (channel).clm. and	US-PGPUB;	15:14
,		((conductive or conducting) adj layer).clm.	EPO; JPO;	
		and (channel near2 region).clm. and (wiring	DERWENT;	
	:	near10 channel).clm. and (first adj	IBM_TDB	
		(conducting or conductive) adj layer).clm.		
179	4	(gate adj wiring).clm. and (gate adj	USPAT;	2004/11/08
	]	electrode).clm. and (channel).clm. and	US-PGPUB;	15:18
		((conductive or conducting) adj layer).clm.	EPO; JPO;	
		and (channel near2 region).clm. and (wiring	DERWENT;	
		near10 channel).clm. and (first adj	IBM_TDB	
		(conducting or conductive) adj layer).clm.	_	
		and (second adj (conducting or conductive)		
		adj layer).clm.		

180	4	(gate adj wiring).clm. and (gate adj	USPAT;	2004/11/08
		electrode).clm. and (channel).clm. and	US-PGPUB;	15:18
		((conductive or conducting) adj layer).clm.	EPO; JPO;	
		and (channel near2 region).clm. and (wiring	DERWENT;	
		near10 channel).clm. and (first adj	IBM_TDB	
		(conducting or conductive) adj layer).clm.	,	•
1		and (second adj (conducting or conductive)		
		adj layer).clm. and (channel near10		
		wiring).clm.		